

CURRENT-LIMITED, POWER-DISTRIBUTION SWITCHES

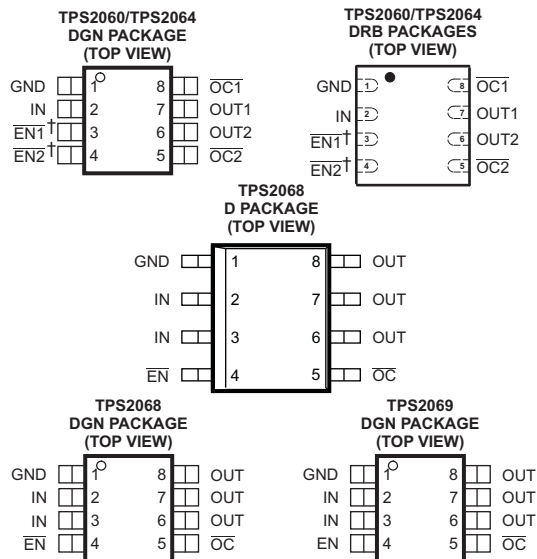
Check for Samples: [TPS2060](#), [TPS2064](#), [TPS2068](#), [TPS2069](#)

FEATURES

- 70-mΩ High-Side MOSFET
- 1.5-A Continuous Current
- Thermal and Short-Circuit Protection
- Accurate Current Limit (1.6 A min, 2.6 A max)
- Operating Range: 2.7 V to 5.5 V
- 0.6-ms Typical Rise Time
- Undervoltage Lockout
- Deglitched Fault Report ($\overline{OC}$)
- No $\overline{OC}$ Glitch During Power Up
- 1-μA Maximum Standby Supply Current
- Reverse Current Blocking
- TPS2060/64 Temperature Range: 0°C to 70°C
- TPS2068/69 DGN Package Temperature Range: –40°C to 85°C
- TPS2068 D Package Temperature Range: 0°C to 70°C
- UL Listed – File No. E169910
- TPS2068/69: CB Certified

APPLICATIONS

- Heavy Capacitive Loads
- Short-Circuit Protections



† All enable inputs are active high for the TPS2064 devices.

DESCRIPTION

The TPS206x power-distribution switches are intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. This device incorporates 70-mΩ N-channel MOSFET power switches for power-distribution systems that require single or dual power switches in a single package. Each switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent ($\overline{OCx}$) logic output low. When continuous heavy overloads and short-circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures that the switch remains off until valid input voltage is present. Current limit is typically 2.1 A.

GENERAL SWITCH CATALOG						
33 mΩ, Single	80 mΩ, Single	80 mΩ, Dual	80 mΩ, Dual	80 mΩ, Triple	80 mΩ, Quad	80 mΩ, Quad
 TPS201xA 0.2 A to 2 A TPS202x 0.2 A to 2 A TPS203x 0.2 A to 2 A	 TPS2014 600 mA TPS2015 1 A TPS2041B 500 mA TPS2051B 500 mA TPS2045A 250 mA TPS2049 100 mA TPS2055A 250 mA TPS2061 1 A TPS2065 1 A TPS2068 1.5 A TPS2069 1.5 A	 TPS2042B 500 mA TPS2052B 500 mA TPS2046B 250 mA TPS2056 250 mA TPS2062 1 A TPS2066 1 A TPS2060 1.5 A TPS2064 1.5 A	 TPS2080 500 mA TPS2081 500 mA TPS2082 500 mA TPS2090 250 mA TPS2091 250 mA TPS2092 250 mA	 TPS2043B 500 mA TPS2053B 500 mA TPS2047B 250 mA TPS2057A 250 mA TPS2063 1 A TPS2067 1 A	 TPS2044B 500 mA TPS2054B 500 mA TPS2048A 250 mA TPS2058 250 mA	 TPS2085 500 mA TPS2086 500 mA TPS2087 500 mA TPS2095 250 mA TPS2096 250 mA TPS2097 250 mA



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

AVAILABLE OPTION AND ORDERING INFORMATION

T_A	ENABLE	RECOMMENDED MAXIMUM CONTINUOUS LOAD CURRENT	TYPICAL SHORT-CIRCUIT CURRENT LIMIT AT 25°C	NUMBER OF SWITCHES	PACKAGED DEVICES ^{(1) (2)}	
					MSOP (DGN)	SON (DRB)
0°C to 70°C	Active low	1.5 A	2.1 A	Dual	TPS2060DGN	TPS2060DRB
	Active high				TPS2064DGN	TPS2064DRB
-40°C to 85°C	Active low			Single	TPS2068DGN	
	Active high				TPS2069DGN	
0°C to 70°C	Active low			Single	TPS2068D	

(1) The package is available taped and reeled. Add an R suffix to device types (e.g., TPS2060DGN).

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted ⁽¹⁾

			UNIT
V _I	Input voltage range, V _{I(IN)}		−0.3 V to 6 V
	Input voltage range, V _{I(ENx)} , V _{I(ENx)}		−0.3 V to 6 V
	Voltage range, V _{I(OC)} , V _{I(OCx)}		−0.3 V to 6 V
V _O	Output voltage range, V _{O(OUT)} , V _{O(OUTx)}		−0.3 V to 6 V
I _O	Continuous output current, I _{O(OUT)} , I _{O(OUTx)}		Internally limited
Continuous total power dissipation			See Dissipation Rating Table
T _J	Operating virtual junction temperature range	TPS2060/64	0°C to 105°C
		TPS2068/69 (DGN Package)	−40°C to 105°C
		TPS2068 (D Package)	0°C to 105°C
T _{stg}	Storage temperature range		−65°C to 150°C
ESD	Electrostatic discharge protection	Human body model MIL-STD-883C	2 kV
		Charge device model (CDM)	500 V

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATING RATING TABLE ⁽¹⁾

PACKAGE	THERMAL RESISTANCE θ_{JA}	$T_A < 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DGN-8 ⁽²⁾		1370 mW	17 mW/°C	600 mW	342 mW
D-8		585.82 mW	5.8582 mW/°C	322.20 mW	234.32 mW
DRB-8 (Low-K) ⁽³⁾	270 °CW	370 mW	3.71 mW/°C	203 mW	148 mW
DRB-8 (High-K) ⁽⁴⁾	60 °CW	1600 mW	16.67 mW/°C	916 mW	866 mW

(1) Heatsink the PowerPad™ per the recommendations of [SLMA002](#). PCB used for recommendations per appendix A4.

(2) See *Recommended Operating Conditions* Table for PowerPad connection guidelines to meet qualifying conditions for CB Certificate.

(3) Soldered PowerPAD on a standard 2-layer PCB without vias for thermal pad. See TI application note [SLMA002](#) for further details.

(4) Soldered PowerPAD on a standard 4-layer PCB with vias for thermal pad. See TI application note [SLMA002](#) for further details.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V_I	Input voltage, $V_{I(IN)}$		2.7	5.5	V
	Input voltage, $V_{I(ENx)}$, $V_{I(ENx)}$		0	5.5	V
I_O	Continuous output current, $I_{O(OUTx)}$		0	1.5	A
T_J	Operating virtual junction temperature	TPS2060/64	0	105	°C
		TPS2068/69 (DGN Package)	–40	105	
		TPS2068 (D Package)	0	105	

(1) The PowerPad must be connected externally to GND pin to meet qualifying conditions for CB Certificate (DGN package only).

ELECTRICAL CHARACTERISTICS

0°C ≤ T_J ≤ 105°C for the TPS2060/64 and TPS2068 (D package), plus –40°C ≤ T_J ≤ 105°C for the TPS2068/69 (DGN package), $V_{I(IN)} = 5.5$ V, $I_O = 1$ A, $V_{I(ENx)} = 0$ V, or $V_{I(ENx)} = 5.5$ V (unless otherwise noted).

PARAMETER		TEST CONDITIONS ⁽¹⁾			MIN	TYP	MAX	UNIT
POWER SWITCH								
r _{DS(on)}	Static drain-source on-state resistance, 5-V operation and 3.3-V operation	V _{I(IN)} = 5 V or 3.3 V, I _O = 1.5 A				70	115	mΩ
	Static drain-source on-state resistance, 2.7-V operation	V _{I(IN)} = 2.7 V, I _O = 1.5 A				75	125	mΩ
t _r	Rise time, output	V _{I(IN)} = 5.5 V	C _L = 1 μF, R _L = 5 Ω	T _J = 25°C		0.6	1.5	ms
		V _{I(IN)} = 2.7 V				0.4	1	
t _f	Fall time, output	V _{I(IN)} = 5.5 V				0.05	0.5	
		V _{I(IN)} = 2.7 V				0.05	0.5	
ENABLE INPUT $\overline{EN}$ OR EN								
V _{IH}	High-level input voltage	2.7 V < V _{I(IN)} < 5.5 V			2			V
V _{IL}	Low-level input voltage	2.7 V < V _{I(IN)} < 5.5 V					0.8	
I _I	Input current	V _{I(ENx)} = 0 V or 5.5 V, V _{I(ENx)} = 0 V or 5.5 V			-0.5		0.5	μA
t _{on}	Turnon time	C _L = 100 μF, R _L = 5 Ω					3	ms
t _{off}	Turnoff time	C _L = 100 μF, R _L = 5 Ω					10	
CURRENT LIMIT								
I _{OS}	Short-circuit output current	V _{I(IN)} = 5 V, OUT connected to GND, device enabled into short-circuit			1.6	2.1	2.6	A
I _{OC_TRIP}	Overcurrent trip threshold	V _{I(IN)} = 5 V, Current ramp (≤ 100 A/s) on OUT		TPS2060/64	3.2		3.9	A
				TPS2068/69	2.3		2.85	
I _{OS} ⁽²⁾	Short-circuit output current	V _{I(IN)} = 5 V, OUT1 and OUT2 connected to GND, Device enabled into short-circuit, current measured at V _{I(IN)}			3.2	4.2	5.2	A
I _{OC_TRIP} ⁽²⁾	Overcurrent trip threshold TPS2060/64	V _{I(IN)} = 5 V, Current ramp (≤ 100 A/s) on OUT1 and OUT2 tied together, current measured at V _{I(IN)}			6.4		7.8	A
I _{OL}	Supply current, low-level output	No load on OUT, V _{I(ENx)} = 5.5 V, or V _{I(ENx)} = 0 V		T _J = 25°C	0.5		1	μA
				Over T _J range	0.5		5	
I _{OH}	Supply current, high-level output TPS2060/64	No load on OUT, V _{I(ENx)} = 0 V, or V _{I(ENx)} = 5.5 V		T _J = 25°C	50		70	μA
				Over T _J range	50		90	
I _{OH}	Supply current, high-level output TPS2068/69	No load on OUT, V _{I(ENx)} = 0 V, or V _{I(ENx)} = 5.5 V		T _J = 25°C	43		60	μA
				Over T _J range	43		70	
I _{lkg}	Leakage current	OUT connected to ground, V _{I(ENx)} = 5.5 V, or V _{I(ENx)} = 0 V			1			μA
	Reverse leakage current	V _{I(OUTx)} = 5.5 V, IN = ground		T _J = 25°C	0.2			μA
UNDERVOLTAGE LOCKOUT								
	Low-level input voltage, IN				2		2.5	V
	Hysteresis, IN	T _J = 25°C			75			mV

(1) Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

(2) This configuration has not been tested for UL certification.

ELECTRICAL CHARACTERISTICS (continued)

0°C ≤ T_J ≤ 105°C for the TPS2060/64 and TPS2068 (D package), plus –40°C ≤ T_J ≤ 105°C for the TPS2068/69 (DGN package), V_{I(IN)} = 5.5 V, I_O = 1 A, V_{I(ENx)} = 0 V, or V_{I(ENx)} = 5.5 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP	MAX	UNIT
OVERCURRENT OCx						
V _{OL(OCx)}	Output low voltage	I _{O(OCx)} = 5 mA			0.4	V
	Off-state current	V _{O(OCx)} = 5 V or 3.3 V			1	μA
	OC deglitch	OCx assertion or deassertion	4	8	15	ms
THERMAL SHUTDOWN⁽³⁾						
	Thermal shutdown threshold		135			°C
	Recovery from thermal shutdown		125			°C
	Hysteresis			10		°C

(3) The thermal shutdown only reacts under overcurrent conditions.

DEVICE INFORMATION

Pin Functions

PINS			I/O	DESCRIPTION
DGN and DRB PACKAGES				
NAME	TPS2060	TPS2064		
$\overline{\text{EN1}}$	3	—	I	Enable input, logic low turns on power switch IN-OUT1
$\overline{\text{EN2}}$	4	—	I	Enable input, logic low turns on power switch IN-OUT2
EN1	—	3	I	Enable input, logic high turns on power switch IN-OUT1
EN2	—	4	I	Enable input, logic high turns on power switch IN-OUT2
GND	1	1		Ground
IN	2	2	I	Input voltage
$\overline{\text{OC1}}$	8	8	O	Overcurrent, open-drain output, active low, IN-OUT1
$\overline{\text{OC2}}$	5	5	O	Overcurrent, open-drain output, active low, IN-OUT2
OUT1	7	7	O	Power-switch output, IN-OUT1
OUT2	6	6	O	Power-switch output, IN-OUT2
	PowerPad	PowerPad		Connect to GND

The block diagram illustrates the internal architecture of the ADXL345 dual-channel digital accelerometer. It features two identical processing channels for each axis, labeled OUT1 and OUT2. Each channel includes a Thermal Sense block, a Driver block, a Current Limit block, a Charge Pump, and a UVLO (Under Voltage Lock Out) block. The Driver and Current Limit blocks are interconnected. The Charge Pump and UVLO blocks are connected to the IN pin. The CS (Chip Select) pin is connected to both the Current Limit and Driver blocks. The Thermal Sense block is connected to the Driver block. The output of the Driver block is connected to the OUT1 and OUT2 pins. The output of the Current Limit block is connected to the OC1 and OC2 pins. The OC1 and OC2 pins are also connected to the Deglitch block. The Deglitch block is connected to the OC1 and OC2 pins. The EN1 and EN2 pins are connected to the Driver and Current Limit blocks. The GND pin is connected to the bottom of the diagram.

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- Arrow.com
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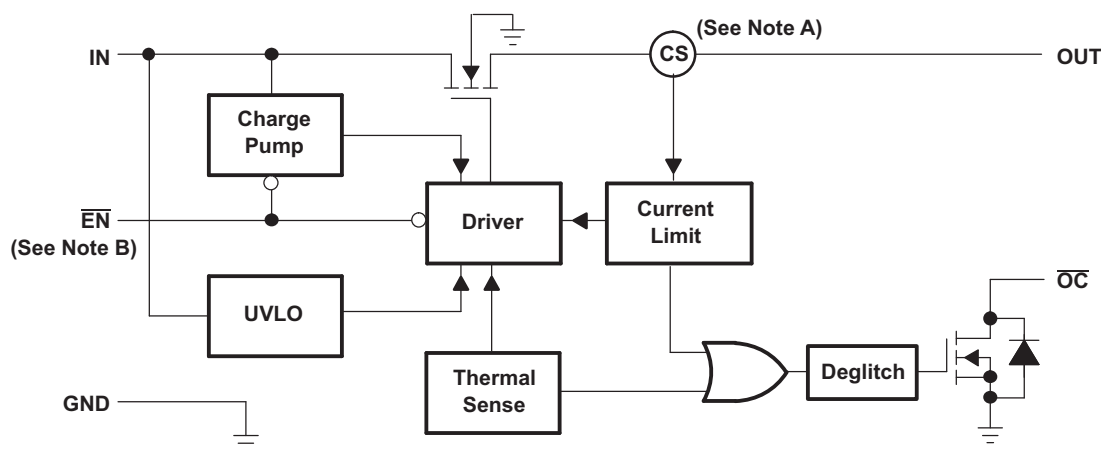
DEVICE INFORMATION

Pin Functions (TPS2068 and TPS2069)

NAME	PINS		I/O	DESCRIPTION
	TPS2068	TPS2069		
$\overline{\text{EN}}$	4	—	I	Enable input, logic low turns on power switch
EN	—	4	I	Enable input, logic high turns on power switch
GND	1	1		Ground
IN	2, 3	2, 3	I	Input voltage
$\overline{\text{OC}}$	5	5	O	Overcurrent, open-drain output, active-low
OUT	6, 7, 8	6, 7, 8	O	Power-switch output
	PowerPad	PowerPad		Connect to GND (DGN Package Only) ⁽¹⁾

(1) See the *Recommended Operating Conditions* Table for PowerPad connection guidelines to meet qualifying conditions for CB Certificate (DGN package only).

Functional Block Diagram (TPS2068 and TPS2069)



- A. Current sense.
B. Active low ($\overline{\text{EN}}$) for TPS2068. Active high (EN) for TPS2069.

PARAMETER MEASUREMENT INFORMATION

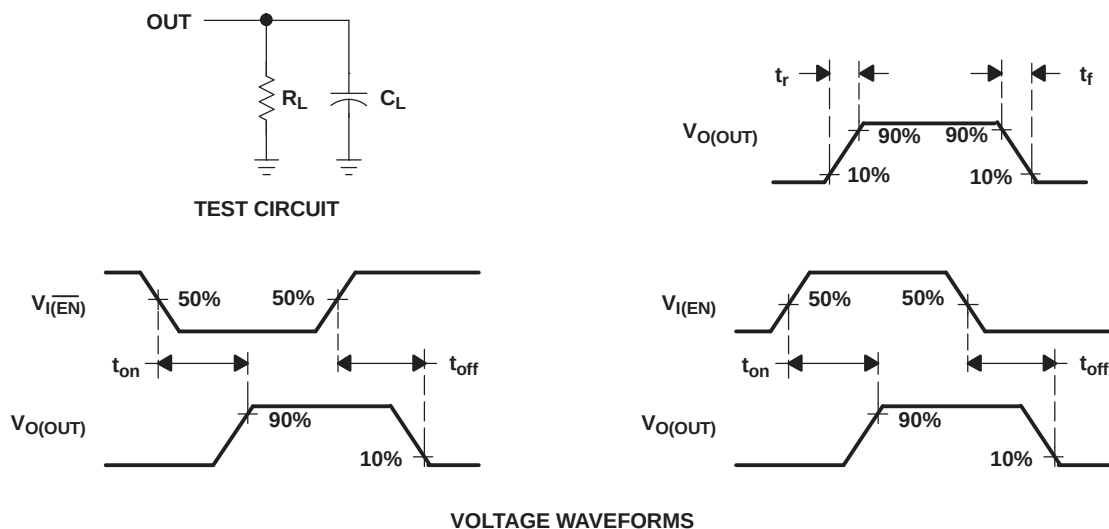


Figure 1. Test Circuit and Voltage Waveforms

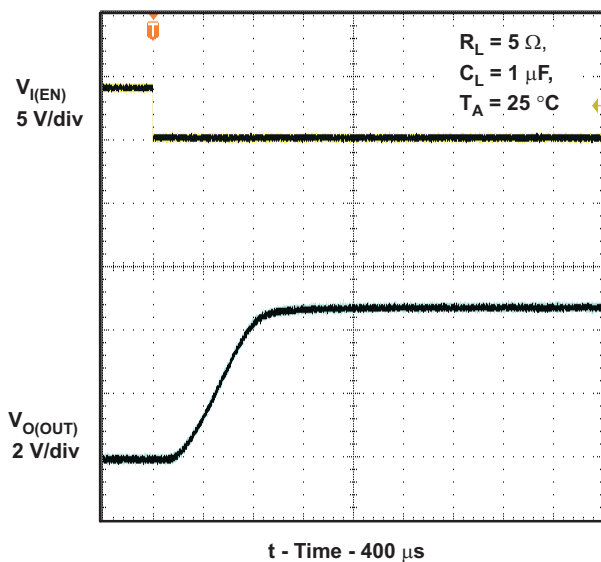


Figure 2. Turnon Delay and Rise Time With 1- μF Load

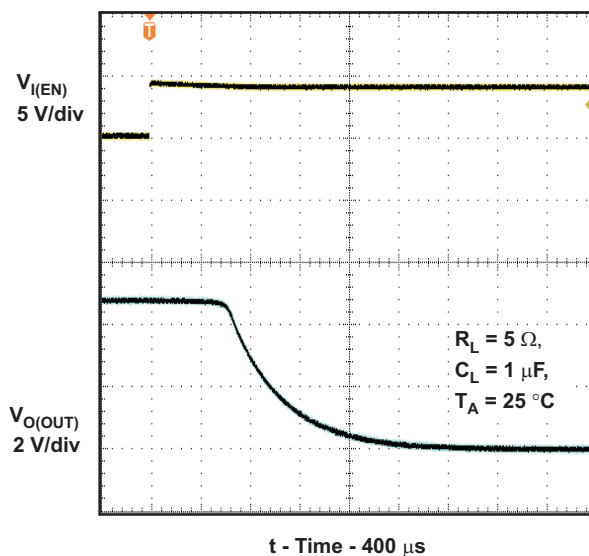


Figure 3. Turnoff Delay and Fall Time With 1- μF Load

PARAMETER MEASUREMENT INFORMATION (continued)

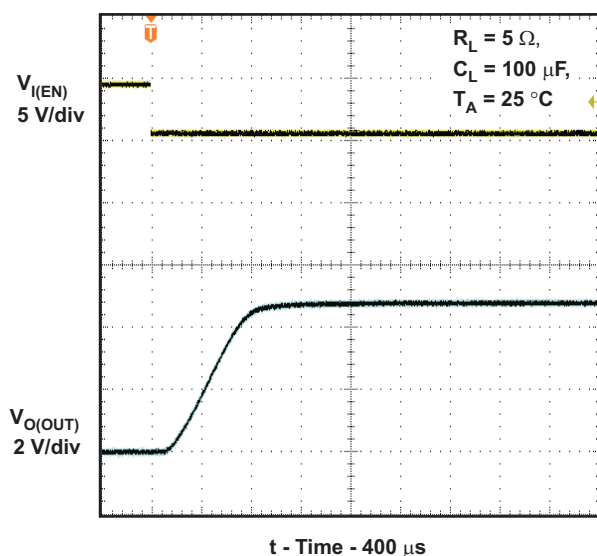


Figure 4. Turnon Delay and Rise Time With 100-μF Load

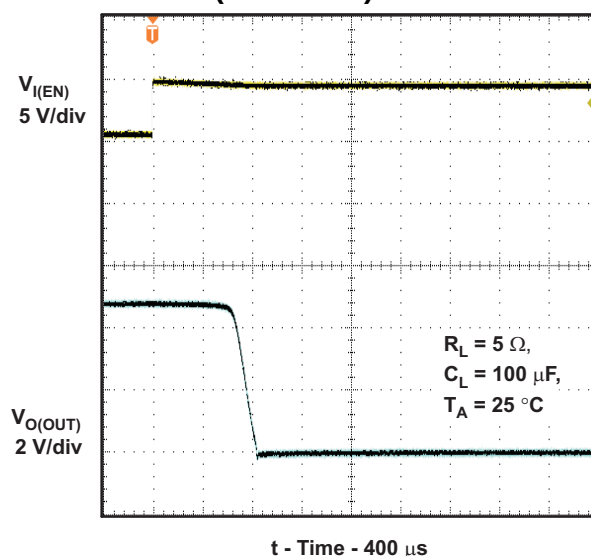


Figure 5. Turnoff Delay and Fall Time With 100-μF Load

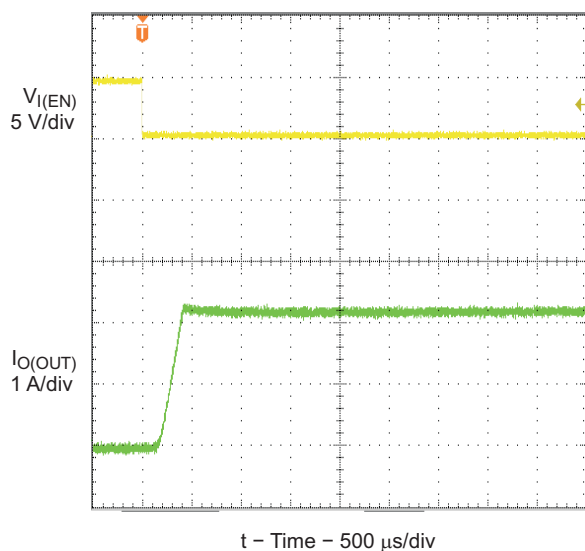


Figure 6. Short-Circuit Current, Device Enabled Into Short

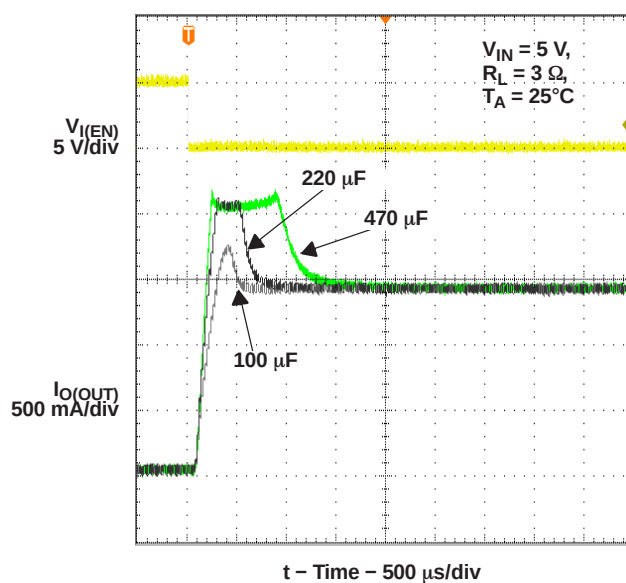


Figure 7. Inrush Current With Different Load Capacitance

PARAMETER MEASUREMENT INFORMATION (continued)

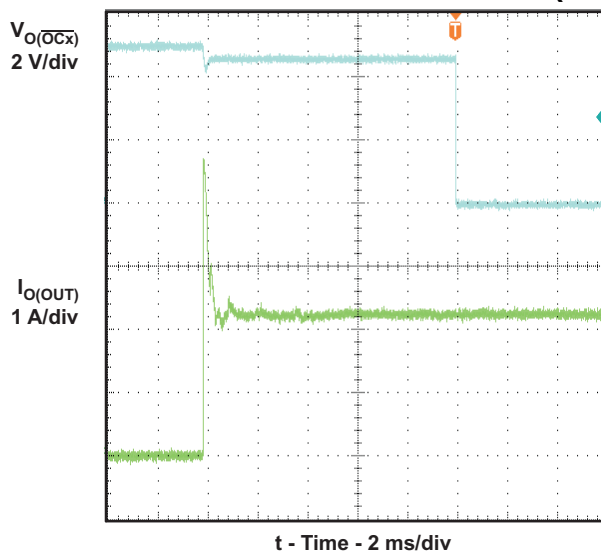


Figure 8. 0.6- Ω Load Connected to Enabled Device

TYPICAL CHARACTERISTICS

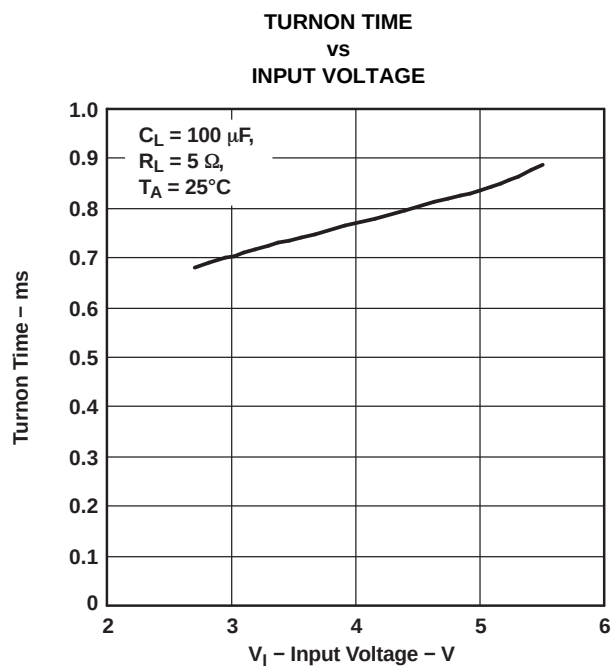


Figure 9.

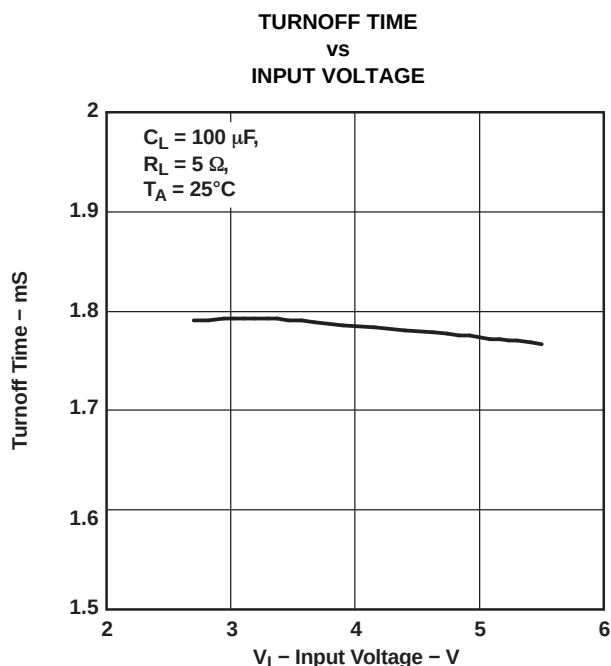


Figure 10.

TYPICAL CHARACTERISTICS (continued)

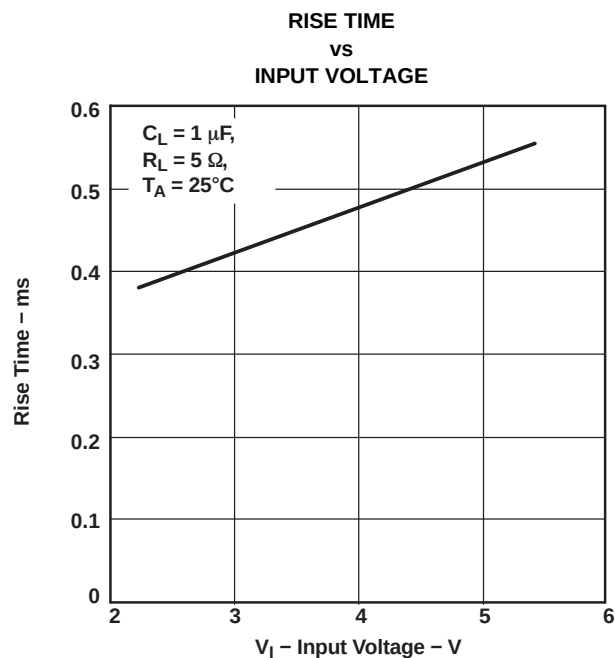


Figure 11.

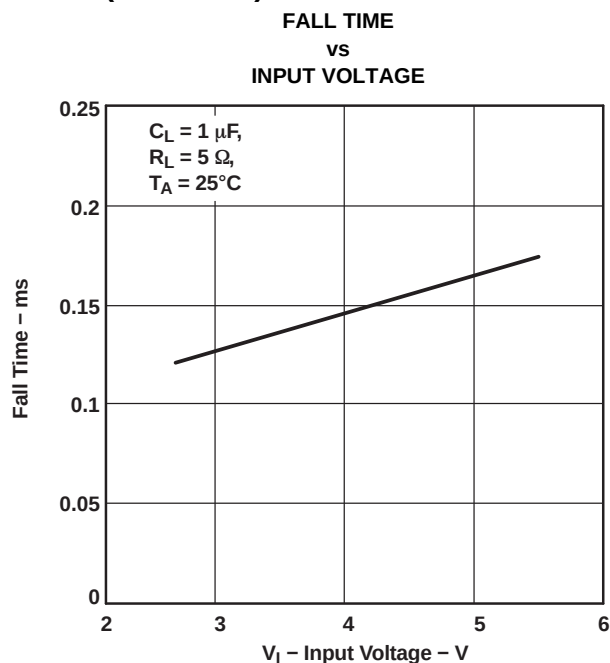


Figure 12.

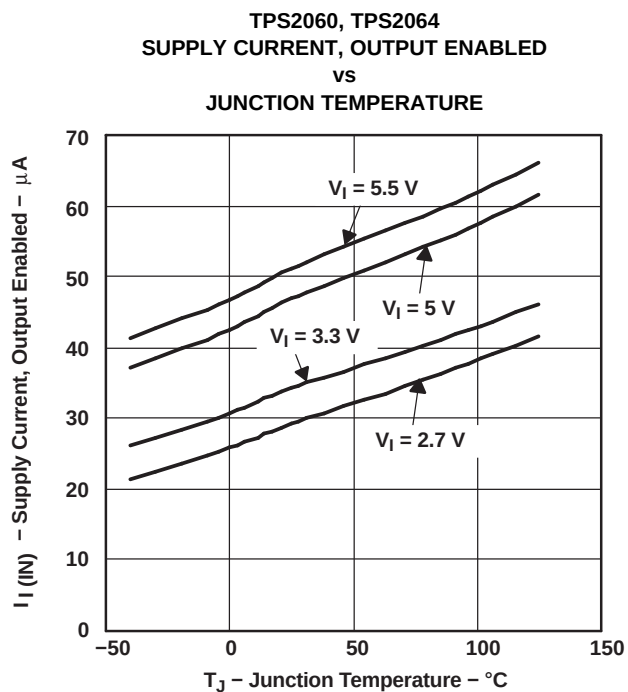


Figure 13.

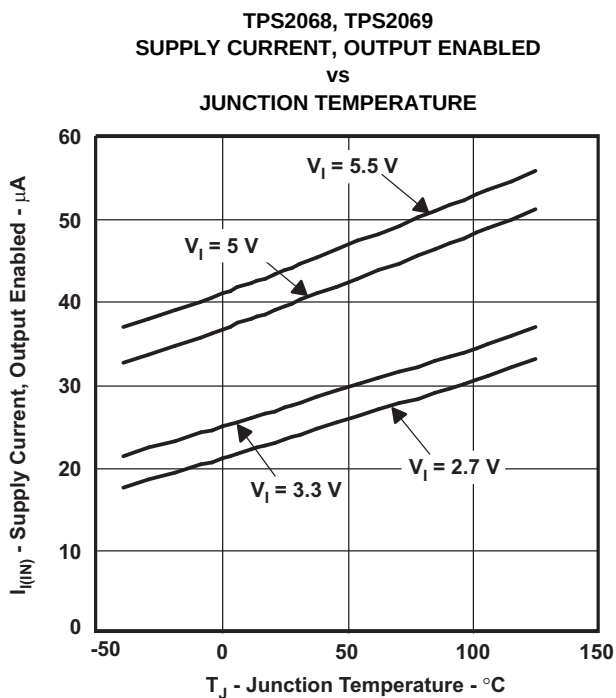


Figure 14.

TYPICAL CHARACTERISTICS (continued)

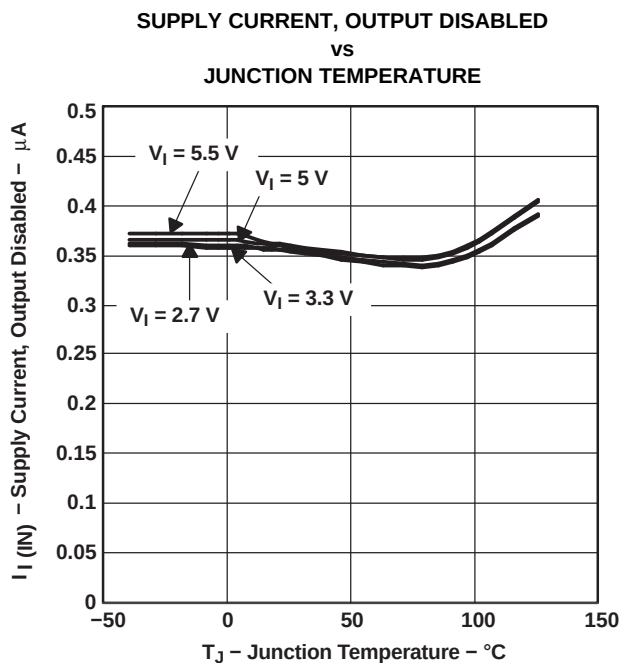


Figure 15.

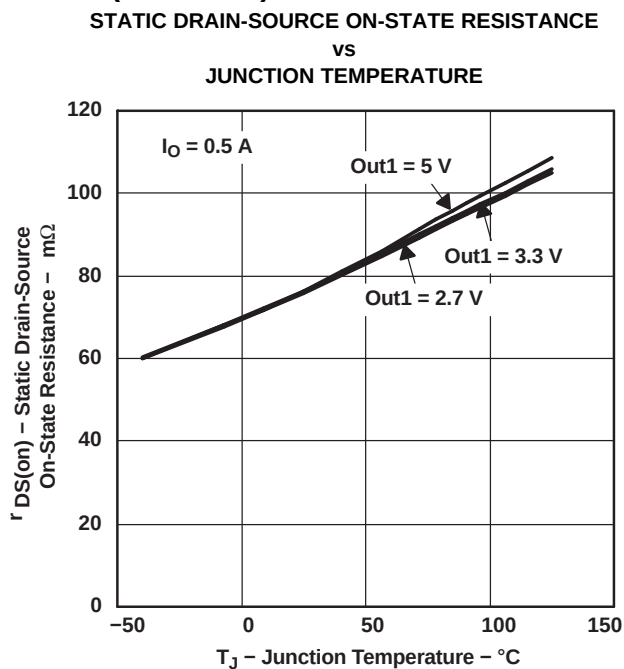


Figure 16.

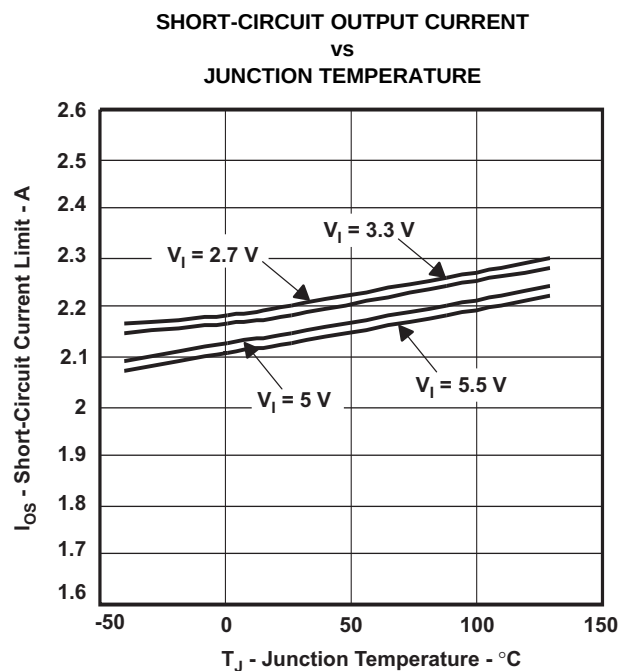


Figure 17.

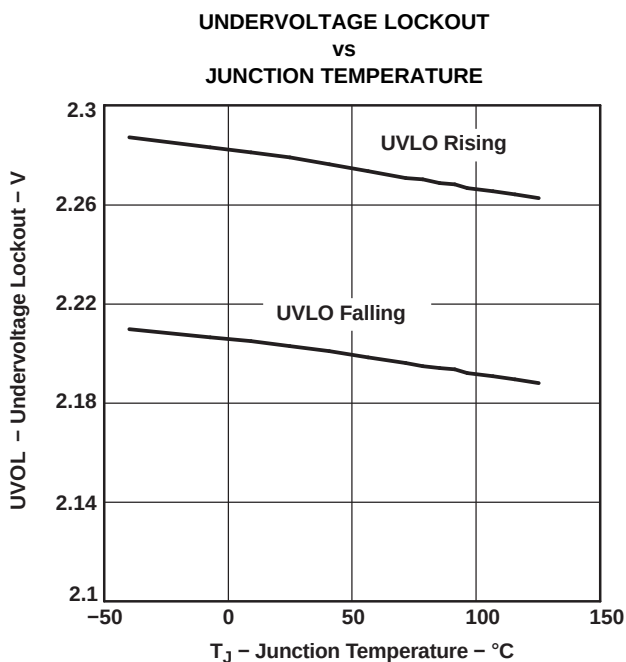
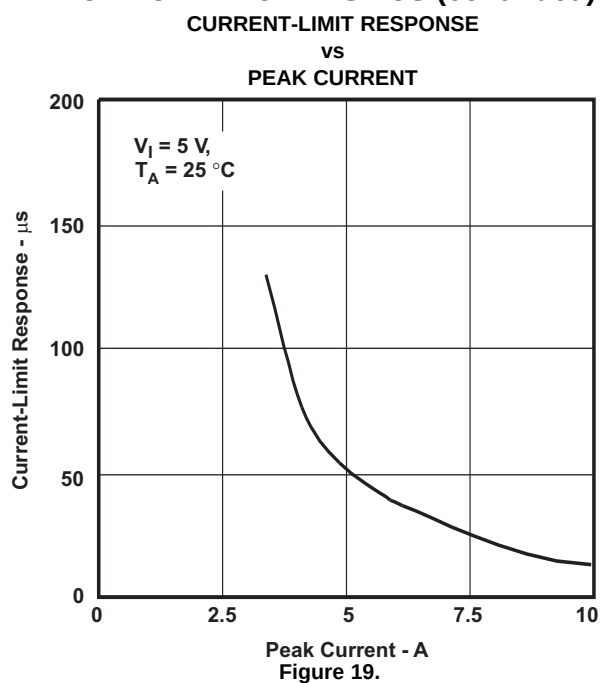


Figure 18.

TYPICAL CHARACTERISTICS (continued)



APPLICATION INFORMATION

POWER-SUPPLY CONSIDERATIONS

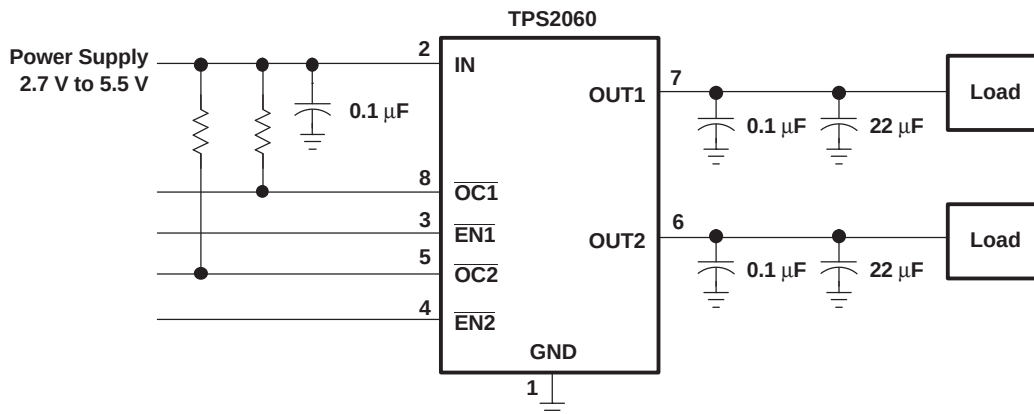


Figure 20. Typical Application

A 0.01- μ F to 0.1- μ F ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01- μ F to 0.1- μ F ceramic capacitor improves the immunity of the device to short-circuit transients.

OVERCURRENT

A sense FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before $V_{I(IN)}$ has been applied (see Figure 6). The TPS206x senses the short and immediately switches into a constant-current output.

In the second condition, a short or an overload occurs while the device is enabled. At the instant the overload occurs, high currents may flow for a short period of time before the current-limit circuit can react (see Figure 8). After the current-limit circuit has tripped (reached the overcurrent trip threshold), the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded. The TPS206x is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

OC RESPONSE

The $\overline{OCx}$ open-drain output is asserted (active low) when an overcurrent or overtemperature shutdown condition is encountered after a 10-ms deglitch timeout. The output remains asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause a momentary overcurrent condition; however, no false reporting on $\overline{OCx}$ occurs due to the 10-ms deglitch circuit. The TPS206x is designed to eliminate false overcurrent reporting. The internal overcurrent deglitch eliminates the need for external components to remove unwanted pulses. $\overline{OCx}$ is not deglitched when the switch is turned off due to an overtemperature shutdown.

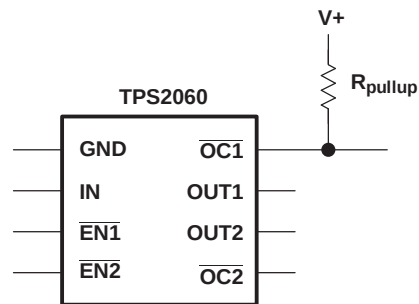


Figure 21. Typical Circuit for the $\overline{OC}$ Pin

POWER DISSIPATION AND JUNCTION TEMPERATURE

The low on-resistance on the N-channel MOSFET allows the small surface-mount packages to pass large currents. The thermal resistance of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. Begin by determining the $r_{DS(on)}$ of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read $r_{DS(on)}$ from Figure 16. Using this value, the power dissipation per switch can be calculated by:

$$P_D = r_{DS(on)} \times I^2$$

Multiply this number by the number of switches being used. This step renders the total power dissipation from the N-channel MOSFETs.

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

T_A = Ambient temperature °C

$R_{\theta JA}$ = Thermal resistance

P_D = Total power dissipation based on number of switches being used.

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

THERMAL PROTECTION

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The TPS206x implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. In an overcurrent or short-circuit condition, the junction temperature rises due to excessive power dissipation. Once the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 10°C, the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The $\overline{OCx}$ open-drain output is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

UNDERVOLTAGE LOCKOUT (UVLO)

An undervoltage lockout ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO also keeps the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. On reinsertion, the power switch is turned on, with a controlled rise time to reduce EMI and voltage overshoots.

UNIVERSAL SERIAL BUS (USB) APPLICATIONS

The universal serial bus (USB) interface is a 12-Mb/s, or 1.5-Mb/s, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (e.g., keyboards, printers, scanners, and mice). The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply.

The USB specification defines the following five classes of devices, each differentiated by power-consumption requirements:

- Hosts/self-powered hubs (SPH)
- Bus-powered hubs (BPH)
- Low-power, bus-powered functions
- High-power, bus-powered functions
- Self-powered functions

SPHs and BPHs distribute data and power to downstream functions. The TPS206x has higher current capability than required by one USB port; so, it can be used on the host side and supplies power to multiple downstream ports or functions.

HOST/SELF-POWERED AND BUS-POWERED HUBS

Hosts and SPHs have a local power supply that powers the embedded functions and the downstream ports (see [Figure 22](#)). This power supply must provide from 5.25 V to 4.75 V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current-limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.

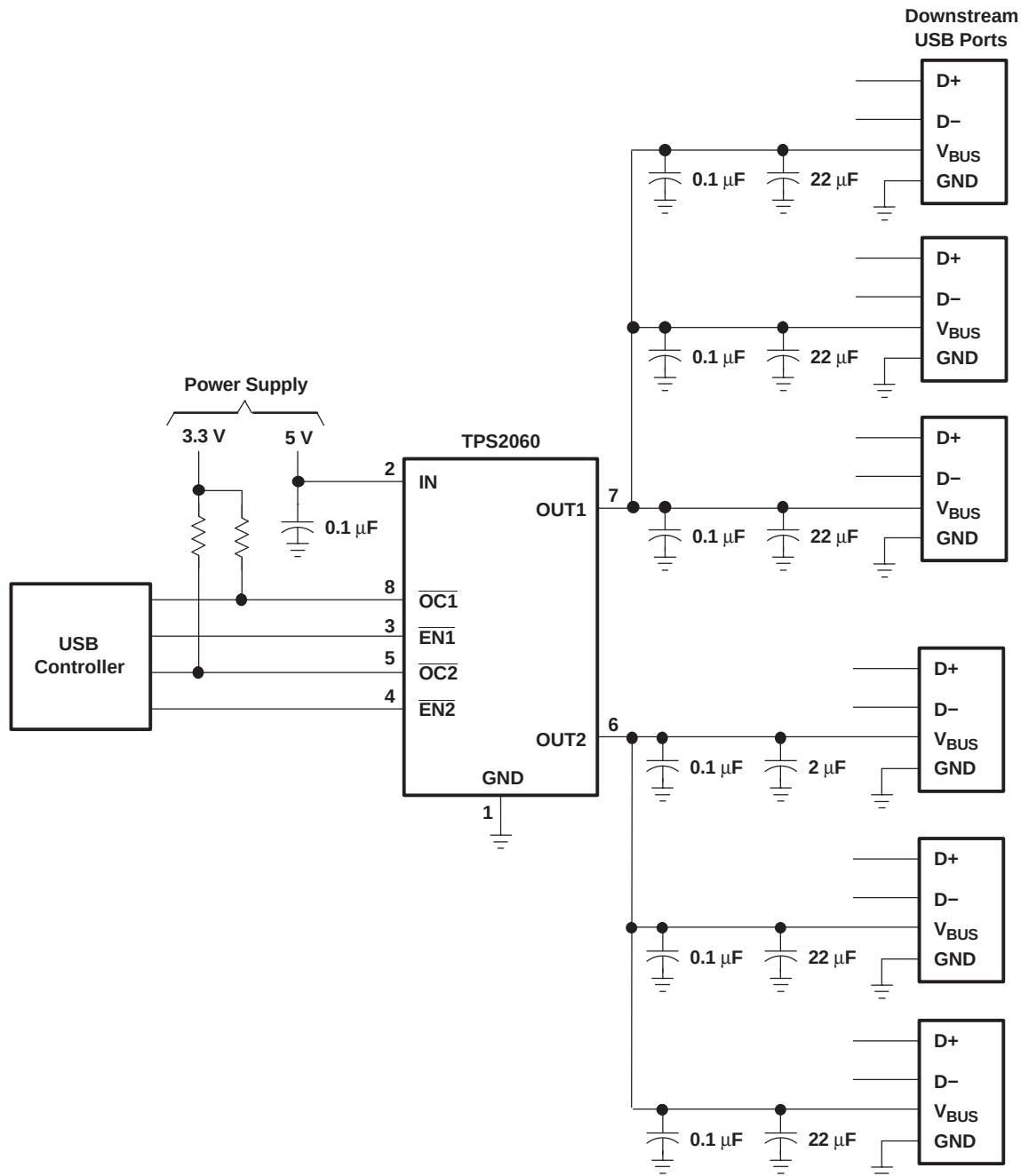
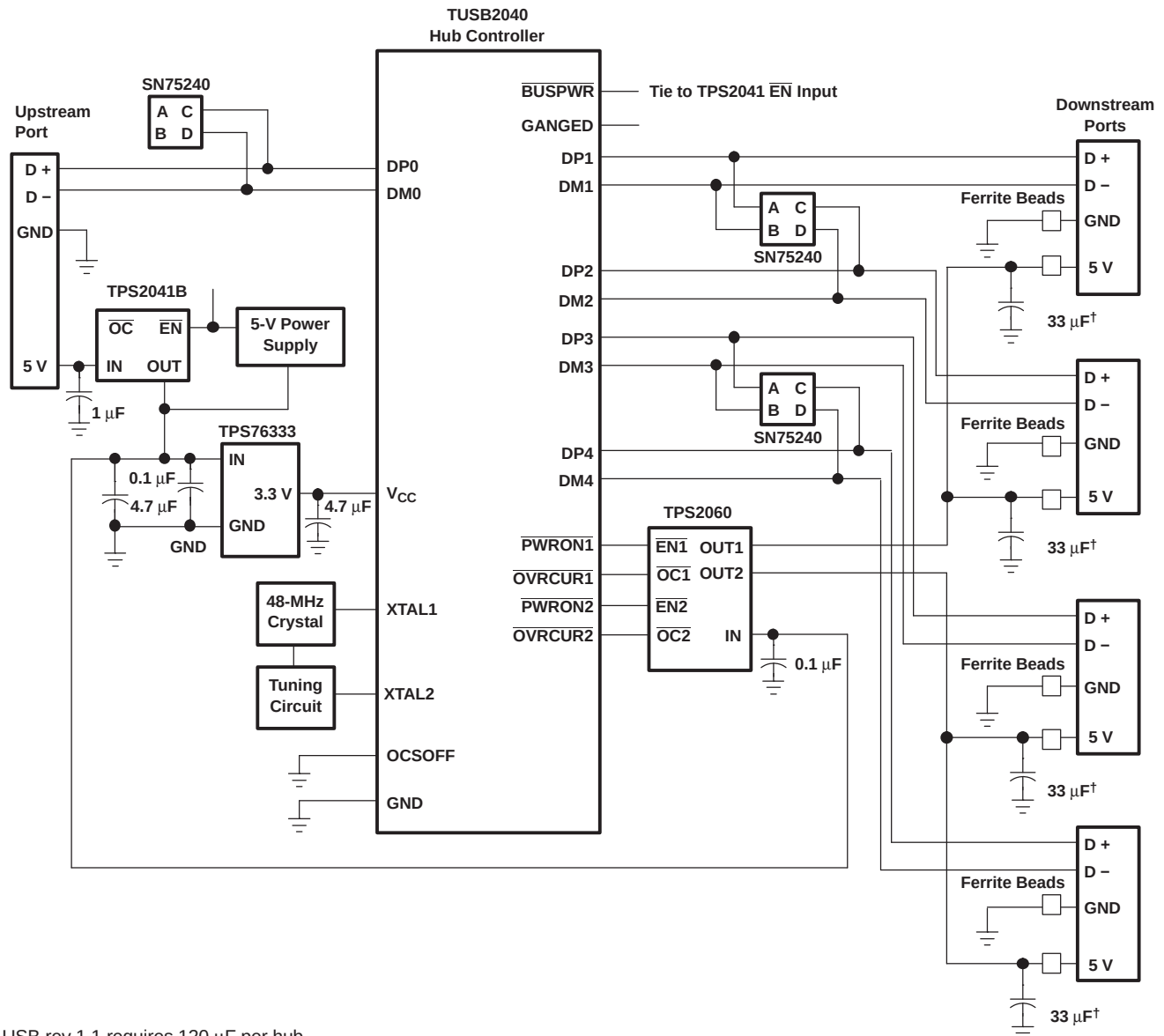


Figure 22. Typical Six-Port USB Host/Self-Powered Hub

BPHs obtain all power from upstream ports and often contain an embedded function. The hubs are required to power up with less than one unit load. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on power up, the power to the embedded function may need to be kept off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than one unit load. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.



† USB rev 1.1 requires 120 µF per hub.

Figure 24. Hybrid Self / Bus-Powered Hub Implementation

GENERIC HOT-PLUG APPLICATIONS

In many applications it may be necessary to remove modules or pc boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the TPS206x, these devices can be used to provide a softer start-up to devices being hot-plugged into a powered system. The UVLO feature of the TPS206x also ensures that the switch is off after the card has been removed, and that the switch is off during the next insertion. The UVLO feature insures a soft start with a controlled rise time for every insertion of the card or module.

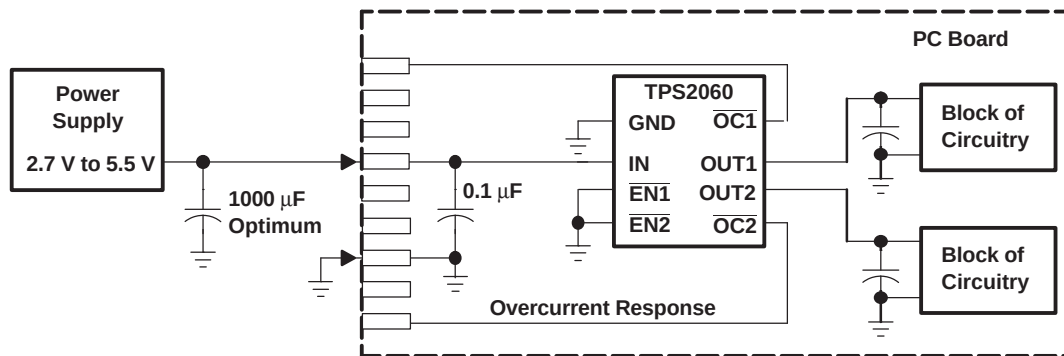


Figure 25. Typical Hot-Plug Implementation

By placing the TPS206x between the V_{CC} input and the rest of the circuitry, the input power reaches these devices first after insertion. The typical rise time of the switch is approximately 1 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.

DETAILED DESCRIPTION

Power Switch

The power switch is an N-channel MOSFET with a low on-state resistance. Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum current of 1.5 A.

Charge Pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires little supply current.

Driver

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage.

Enable ($\overline{ENx}$)

The logic enable disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current. The supply current is reduced to less than 1 μ A when a logic high is present on $\overline{ENx}$, or when a logic low is present on $\overline{ENx}$. A logic zero input on $\overline{ENx}$, or a logic high input on $\overline{ENx}$ restores bias to the drive and control circuits and turns the switch on. The enable input is compatible with both TTL and CMOS logic levels.

Overcurrent ($\overline{OCx}$)

The $\overline{OCx}$ open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output remains asserted until the overcurrent or overtemperature condition is removed. A 10-ms deglitch circuit prevents the $\overline{OCx}$ signal from oscillation or false triggering. If an overtemperature shutdown occurs, the $\overline{OCx}$ is asserted instantaneously.

Current Sense

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant-current mode and holds the current constant while varying the voltage on the load.

Thermal Sense

The TPS206x implements a thermal sensing to monitor the operating temperature of the power distribution switch. In an overcurrent or short-circuit condition the junction temperature rises. When the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns off the switch, thus preventing the device from damage. Hysteresis is built into the thermal sense, and after the device has cooled approximately 10 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed. The open-drain false reporting output ($\overline{\text{OCx}}$) is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

Undervoltage Lockout

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2 V, a control signal turns off the power switch.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS2060DGN	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	0 to 105	2060
TPS2060DGNR	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	0 to 105	2060
TPS2060DRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 105	2060
TPS2060DRBT	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2060
TPS2064DGN	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	0 to 105	2064
TPS2064DGNR	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	0 to 105	2064
TPS2064DRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 105	2064
TPS2064DRBT	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 105	2064
TPS2068D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 105	2068
TPS2068DGN	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	2068
TPS2068DGNR	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	2068
TPS2068DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 105	2068
TPS2069DGN	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	2069
TPS2069DGNR	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	2069

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

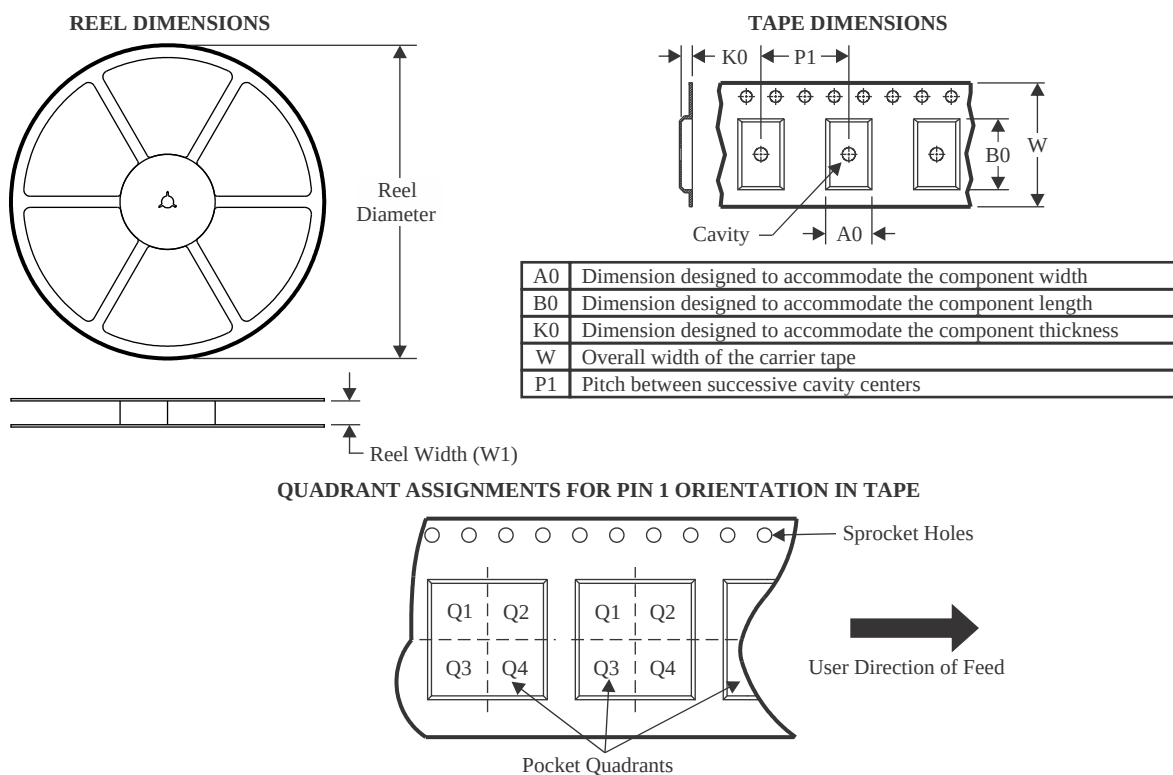
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

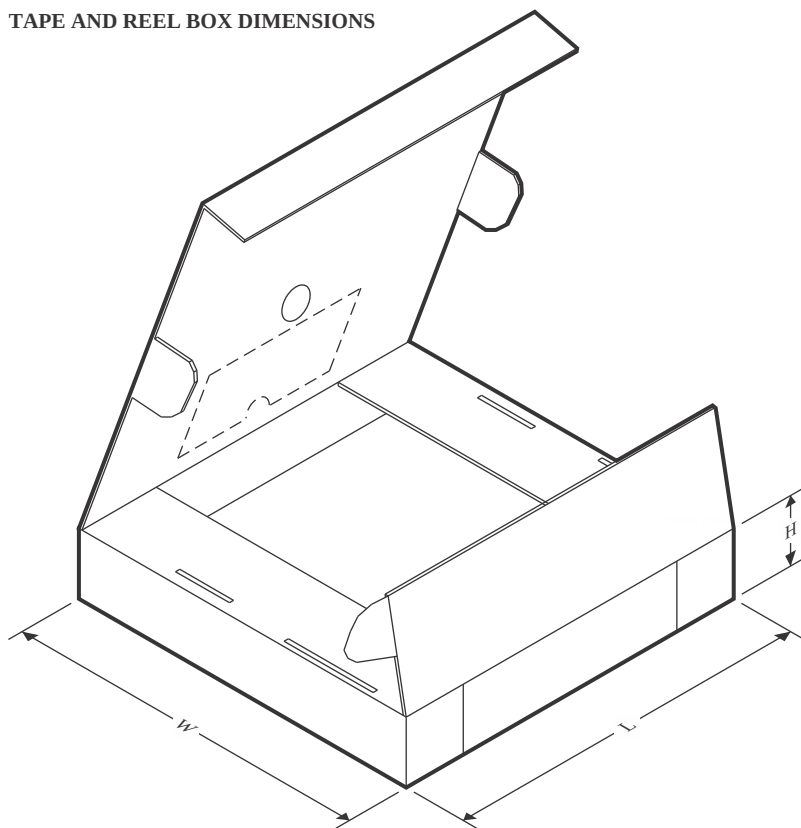
TAPE AND REEL INFORMATION



*All dimensions are nominal

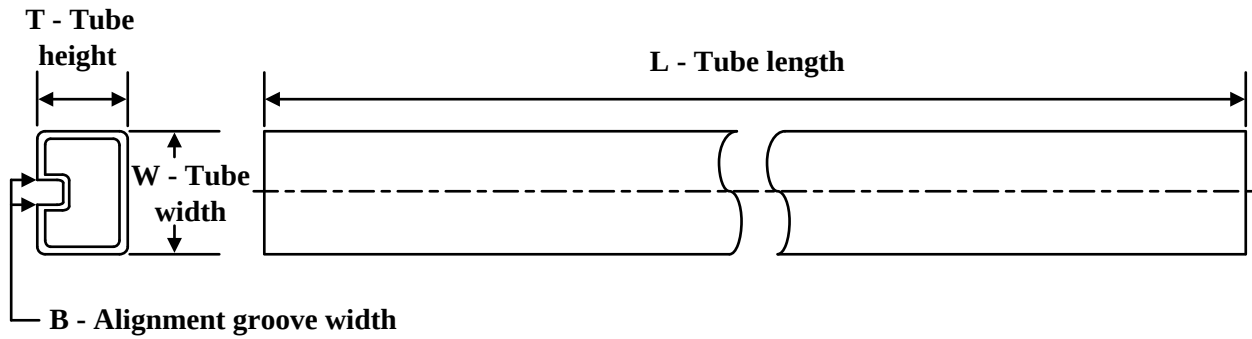
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2060DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2060DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2060DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2060DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2064DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2064DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2064DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2064DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2068DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2068DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2068DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2069DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2069DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2060DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
TPS2060DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2060DRBR	SON	DRB	8	3000	346.0	346.0	35.0
TPS2060DRBT	SON	DRB	8	250	200.0	183.0	25.0
TPS2064DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
TPS2064DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2064DRBR	SON	DRB	8	3000	346.0	346.0	35.0
TPS2064DRBT	SON	DRB	8	250	200.0	183.0	25.0
TPS2068DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2068DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
TPS2068DR	SOIC	D	8	2500	340.5	336.1	25.0
TPS2069DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
TPS2069DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0

TUBE


*All dimensions are nominal

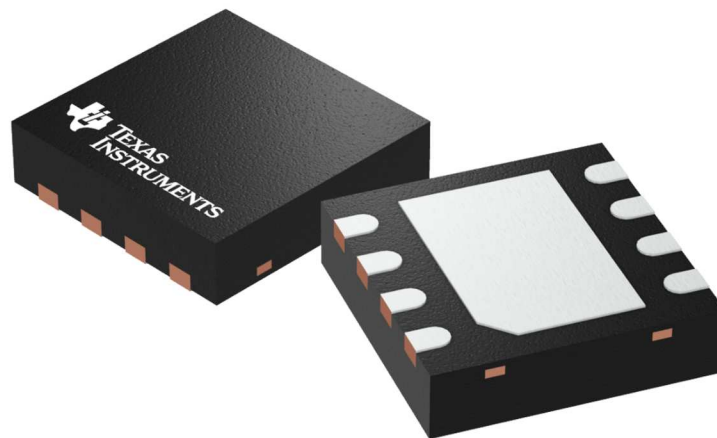
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TPS2060DGN	DGN	HVSSOP	8	80	330	6.55	500	2.88
TPS2060DGN	DGN	HVSSOP	8	80	322	6.55	1000	3.01
TPS2064DGN	DGN	HVSSOP	8	80	330	6.55	500	2.88
TPS2064DGN	DGN	HVSSOP	8	80	322	6.55	1000	3.01
TPS2068D	D	SOIC	8	75	507	8	3940	4.32
TPS2068DGN	DGN	HVSSOP	8	80	330	6.55	500	2.88
TPS2068DGN	DGN	HVSSOP	8	80	322	6.55	1000	3.01
TPS2069DGN	DGN	HVSSOP	8	80	330	6.55	500	2.88
TPS2069DGN	DGN	HVSSOP	8	80	322	6.55	1000	3.01
TPS2069DGNG4	DGN	HVSSOP	8	80	330	6.55	500	2.88
TPS2069DGNG4	DGN	HVSSOP	8	80	322	6.55	1000	3.01

DRB 8

GENERIC PACKAGE VIEW

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203482/L





VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

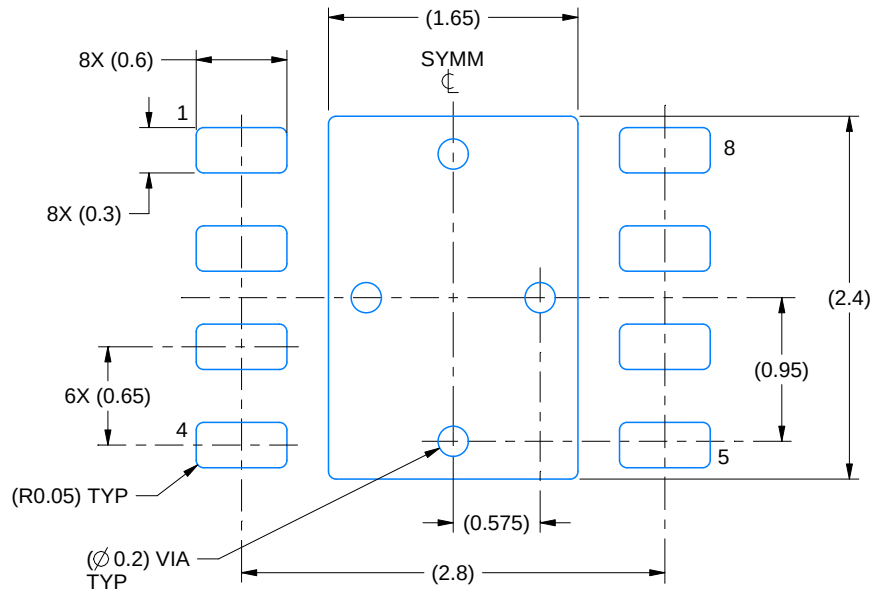


1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

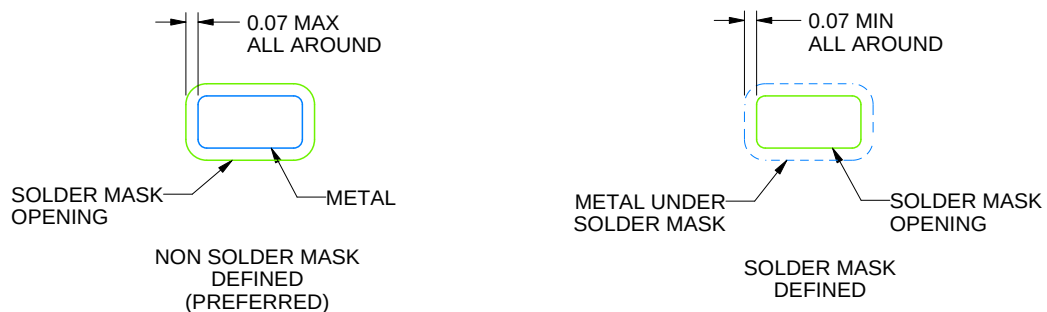
DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

4218876/A 12/2017

NOTES: (continued)

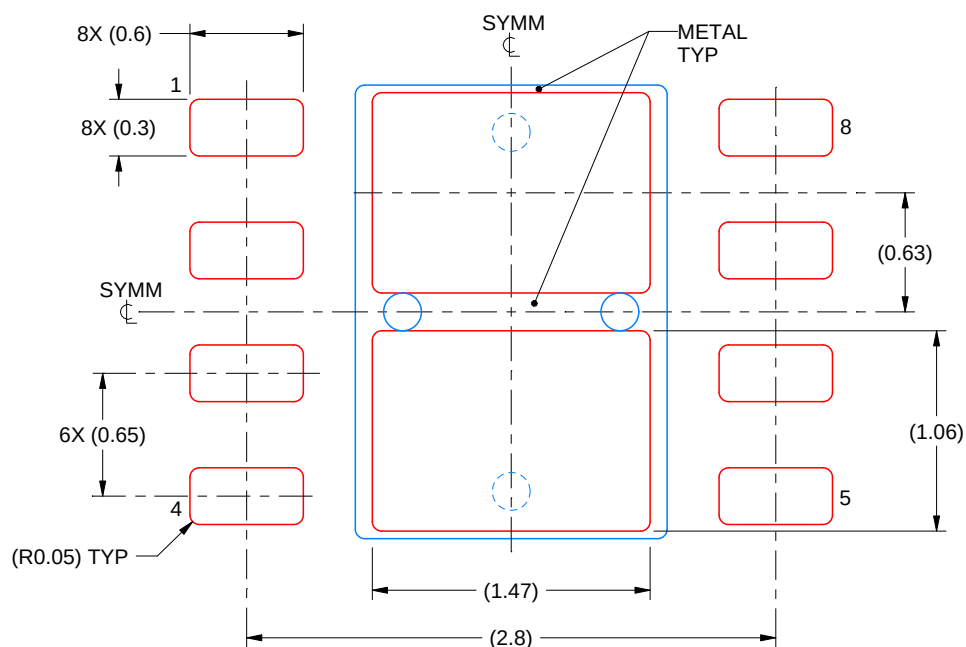
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sl原因271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
81% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

4218876/A 12/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

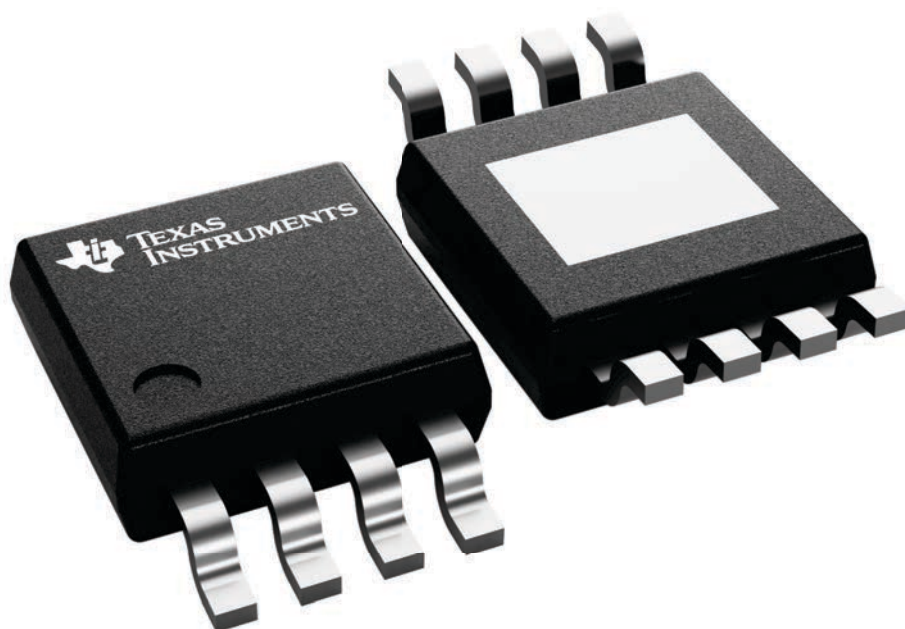
DGN 8

PowerPAD™ HVSSOP - 1.1 mm max height

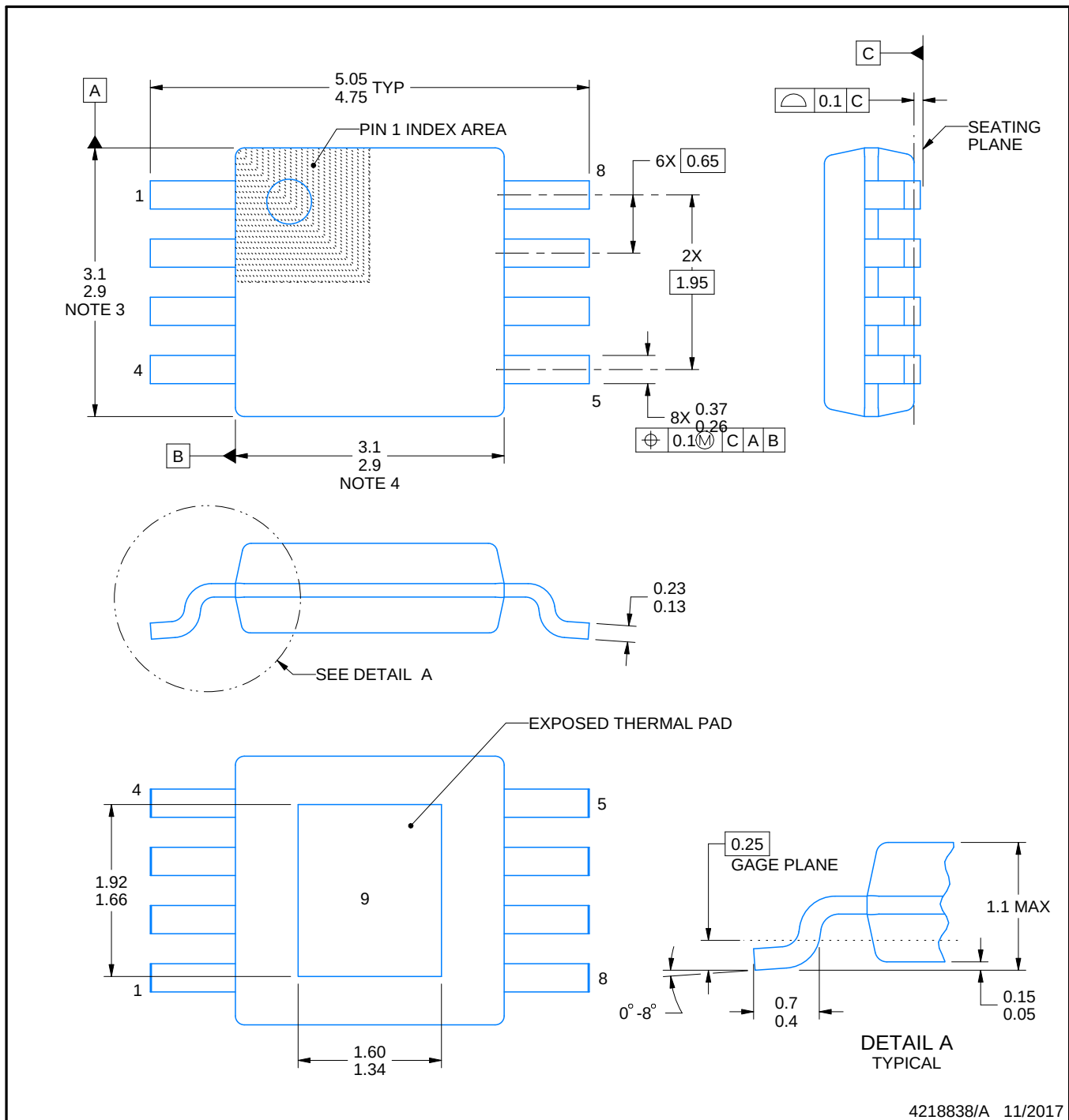
3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4225482/B



4218838/A 11/2017

NOTES:

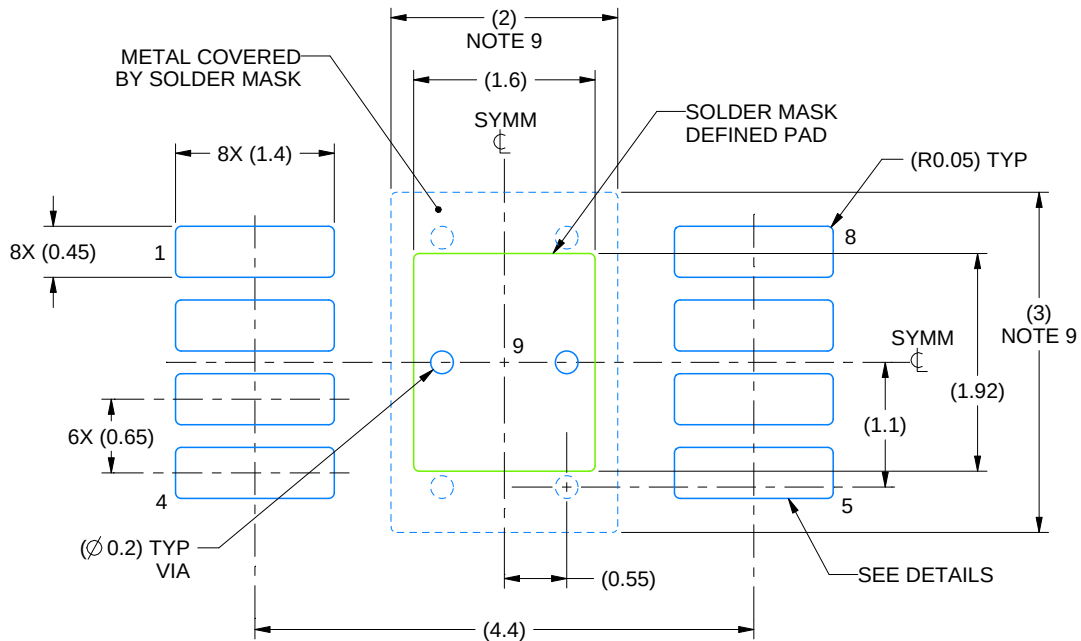
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

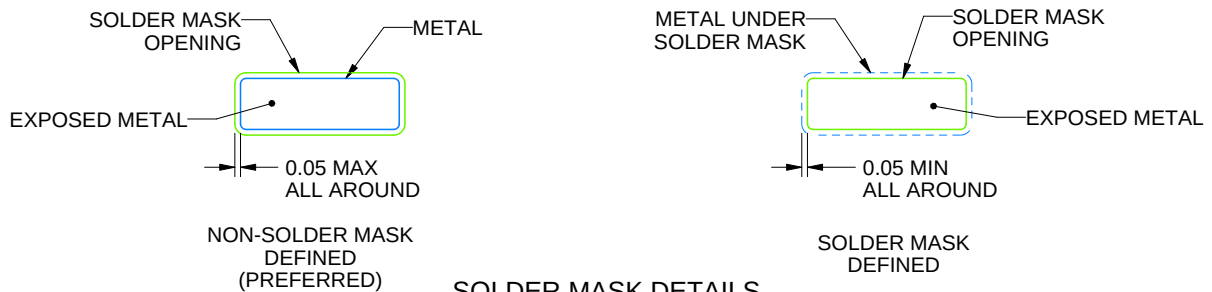
DGN0008C

HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4218838/A 11/2017

NOTES: (continued)

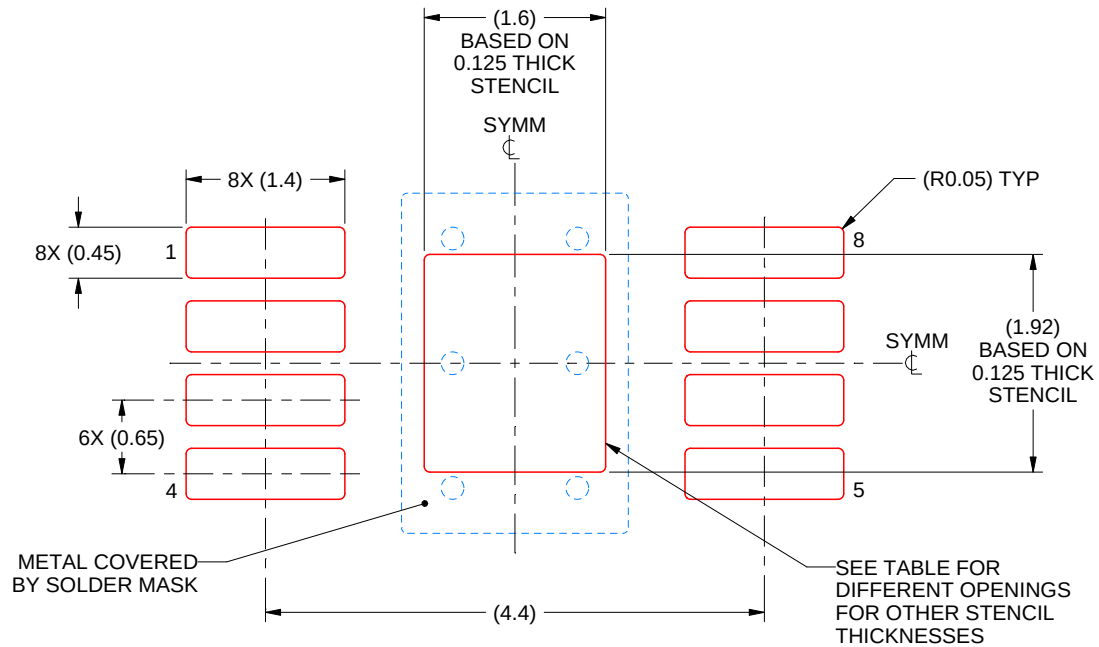
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGN0008C

HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



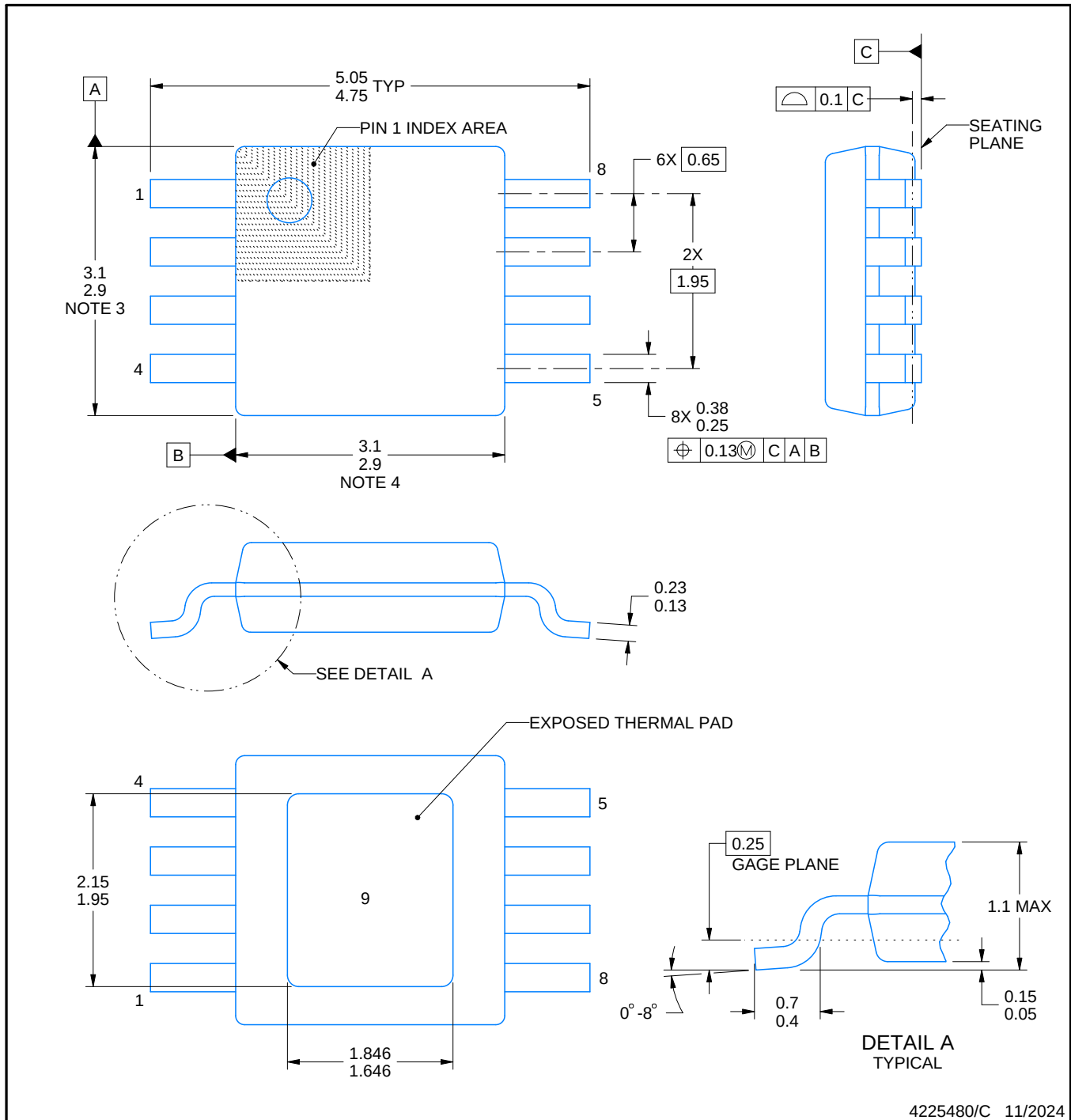
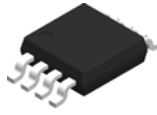
SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.79 X 2.15
0.125	1.60 X 1.92 (SHOWN)
0.15	1.46 X 1.75
0.175	1.35 X 1.62

4218838/A 11/2017

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.



4225480/C 11/2024

NOTES:

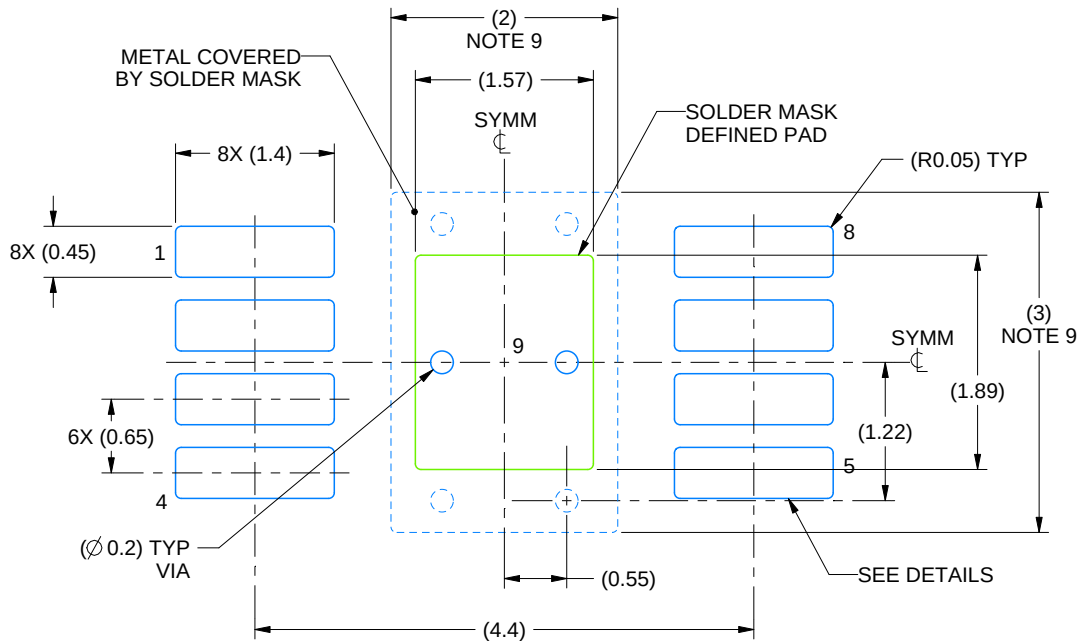
PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

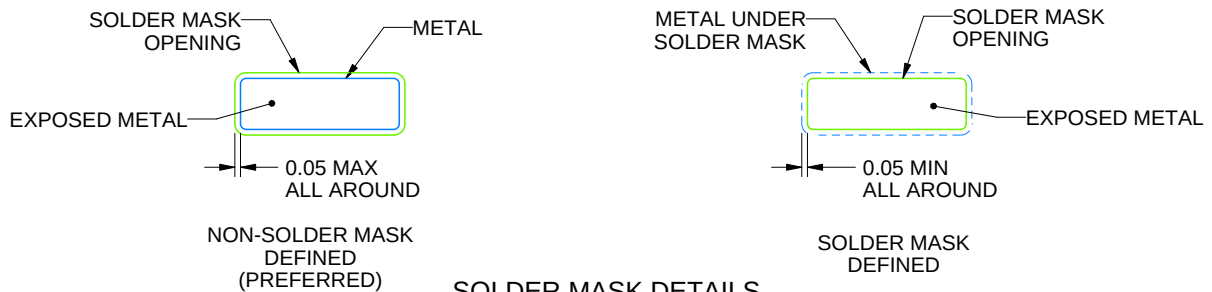
DGN0008G

PowerPAD™ HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4225480/C 11/2024

NOTES: (continued)

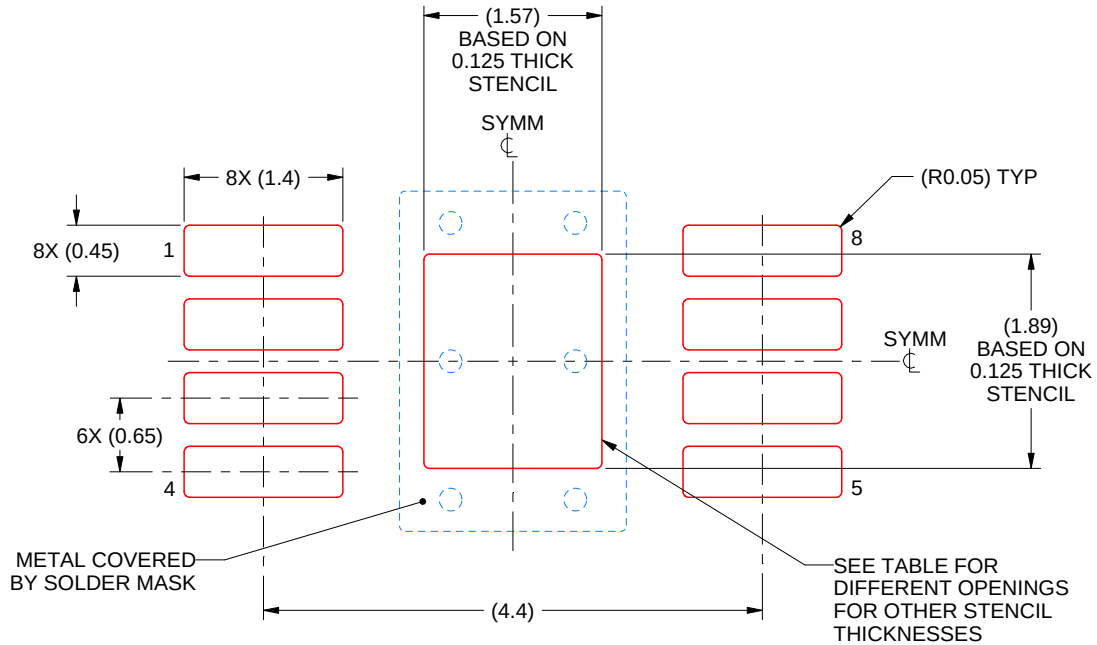
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGN0008G

PowerPAD™ HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



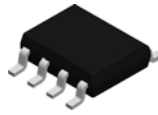
SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

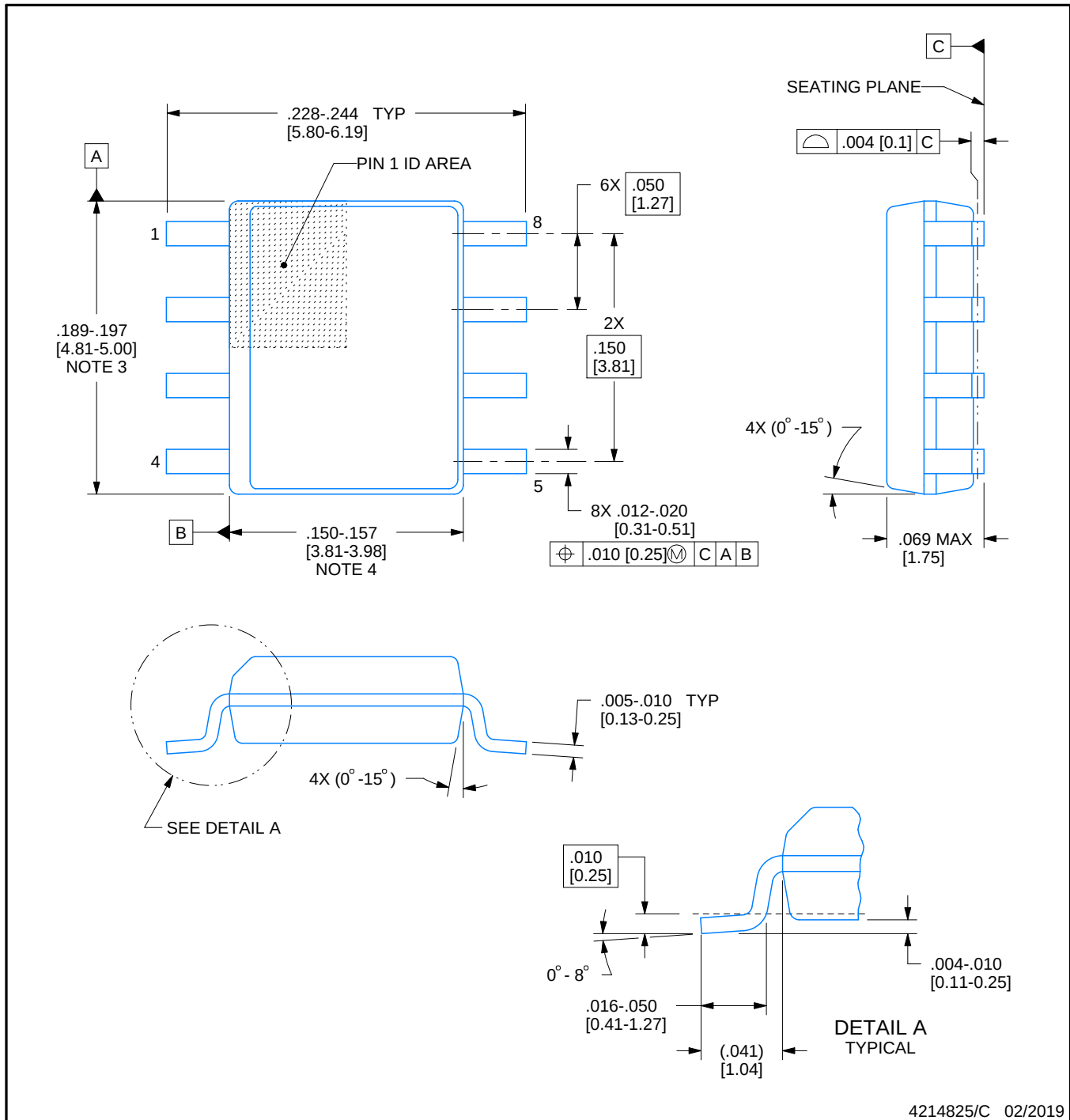
4225480/C 11/2024

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

D0008A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

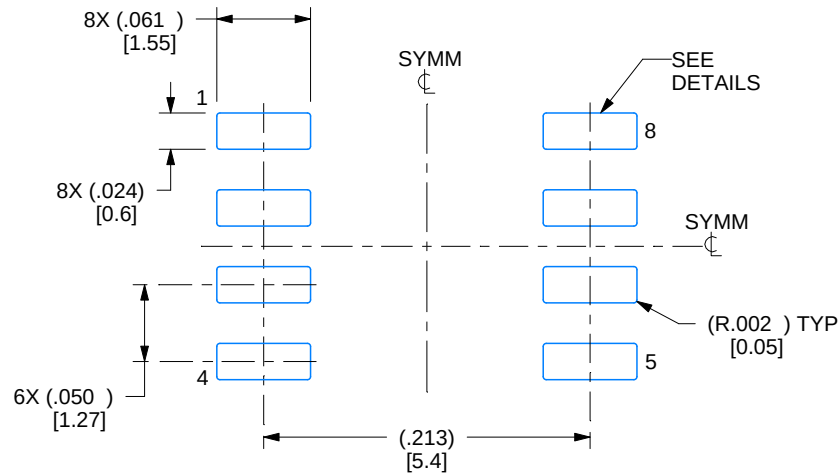
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

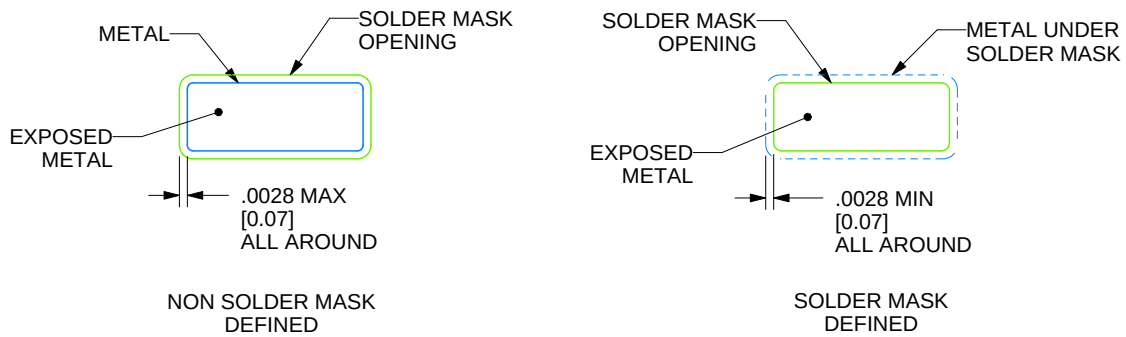
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

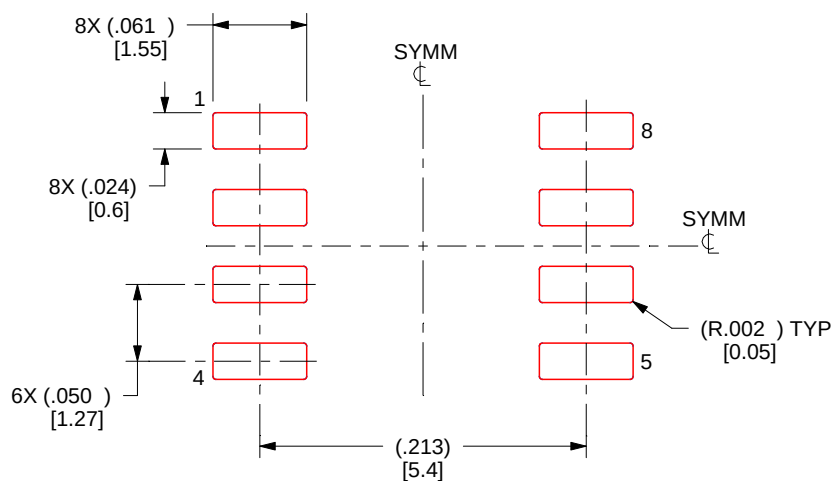
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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